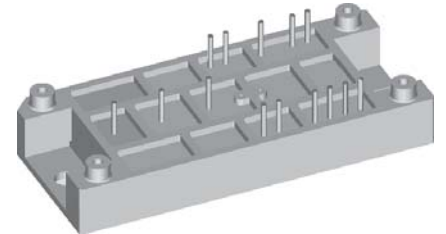
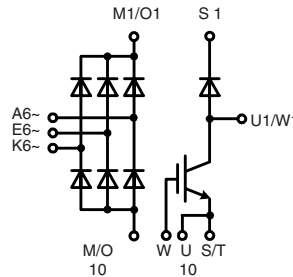


# Three Phase Rectifier Bridge with IGBT and Fast Recovery Diode for Braking System

**$V_{RRM} = 1200/1600 \text{ V}$**   
 **$I_{dAVM} = 188 \text{ A}$**

## Preliminary Data

$V_{RRM}$	Type	$V_{RRM}$	Type
V		V	
1200	VUB 120-12 NO2	1600	VUB 120-16 NO2
1200	VUB 160-12 NO2	1600	VUB 160-16 NO2



Symbol	Conditions	Maximum Ratings		
$V_{RRM}$		1200/1600	V	
$I_{dAVM}$	$T_C = 80^\circ\text{C}$ , rect., $d = 1/3$	188	A	
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	1100	A	
	$T_{VJ} = 150^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	960	A	
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	6050	A	
	$T_{VJ} = 150^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	4610	A	
$P_{tot}$	$T_C = 25^\circ\text{C}$ per diode	160	W	
$V_{CES}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$ Continuous	<b>VUB 120</b>	<b>VUB160</b>	
		1200	1200	
$V_{GE}$		$\pm 20$	$\pm 20$	
$I_{C25}$	$T_C = 25^\circ\text{C}$ , DC	140	177	
		$T_C = 80^\circ\text{C}$ , DC	100	125
		$T_C = 80^\circ\text{C}$ , $d = 0.5$	95	95
$I_{C80}$				
$I_{CM}$	$t_p = \text{Pulse width limited by } T_{VJM}$	280	350	
$P_{tot}$	$T_C = 25^\circ\text{C}$	570	690	
$V_{RRM}$	$T_C = 80^\circ\text{C}$ , rect. $d = 1/2$	1200	V	
		$I_{FAV}$	34	A
		$I_{FRMS}$	48	A
		$I_{FSM}$		
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ , $t = 10 \text{ ms}$	200	A	
	$T_{VJ} = 150^\circ\text{C}$ , $t = 10 \text{ ms}$	180	A	
$P_{tot}$	$T_C = 25^\circ\text{C}$	140	W	
$T_{VJ}$		-40...+150	$^\circ\text{C}$	
$T_{VJM}$		150	$^\circ\text{C}$	
$T_{stg}$		-40...+125	$^\circ\text{C}$	
$V_{ISOL}$	50/60 Hz	$t = 1 \text{ min}$	3000	V~
	$I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ s}$	3600	V~
$M_d$	Mounting torque (M5) (10-32 UNF)	2-2.5	Nm	
		18-22	lb.in.	
$d_s$	Creep distance on surface	12.7	mm	
$d_A$	Strike distance in air	9.4	mm	
$a$	Maximum allowable acceleration	50	$\text{m/s}^2$	
Weight	typ.	80	g	

## Features

- Soldering connections for PCB mounting
- Isolation voltage 3600 V~
- Ultrafast diode
- Convenient package outline
- UL registered E 72873
- Case and potting UL94 V-0

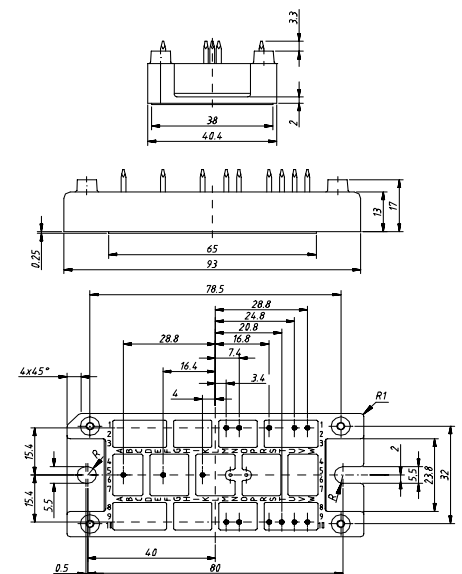
## Applications

- Drive Inverters with brake system

## Advantages

- 2 functions in one package
- Easy to mount with two screws
- Suitable for wave soldering
- High temperature and power cycling capability

## Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions.

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Symbol	Conditions	Characteristic Values ( $T_{VJ} = 25^{\circ}\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$I_R$	$V_R = V_{RRM}, T_{VJ} = 25^{\circ}\text{C}$			0.3 mA
	$V_R = V_{RRM}, T_{VJ} = 150^{\circ}\text{C}$			5 mA
$V_F$	$I_F = 150 \text{ A}, T_{VJ} = 25^{\circ}\text{C}$			1.46 V
$V_{T0}$	For power-loss calculations only			0.87 V
$r_T$	$T_{VJ} = 150^{\circ}\text{C}$			4.0 mΩ
$R_{thJC}$	per diode			0.6 K/W
$R_{thCH}$			0.2	K/W
$V_{BR(CES)}$	$V_{GS} = 0 \text{ V}, I_C = 1 \text{ mA}$	1200		V
	$I_C = 4 \text{ mA}$	4.5		6.5 V
$I_{CES}$	$V_{CE} = 1200 \text{ V}, T_{VJ} = 25^{\circ}\text{C}$			0.2 mA
	$T_{VJ} = 125^{\circ}\text{C}$			1 mA
$V_{CEsat}$	$V_{GE} = 15 \text{ V}, I_C = 50 \text{ A}$	VUB 120		2.1 V
	$I_C = 75 \text{ A}$	VUB 160		2.2 V
$t_{SC}$ (SCSOA)	$V_{GE} = 15 \text{ V}, V_{CE} = 900 \text{ V}, T_{VJ} = 125^{\circ}\text{C},$ $R_G = 15/10 \Omega, \text{ non repetitive}$			10 μs
RBSOA	$V_{GE} = 15 \text{ V}, V_{CE} = 1200 \text{ V}, T_{VJ} = 125^{\circ}\text{C},$ Clamped Inductive load, $L = 100 \mu\text{H}$			
$C_{ies}$	$V_{CE} = 25 \text{ V}, f = 1 \text{ MHz}, V_{GE} = 0 \text{ V}$	VUB 120	5.7	nF
		VUB 160	7.4	nF
$t_{d(on)}$	$V_{CE} = 600 \text{ V}, I_C = 50/75 \text{ A}$ $V_{GE} = 15 \text{ V}, R_G = 15/10 \Omega$ Inductive load; $L = 100 \mu\text{H}$ $T_{VJ} = 125^{\circ}\text{C}$	VUB 120	170	ns
$t_{d(on)}$		VUB 160	330	ns
$t_{d(off)}$		VUB 120	680	ns
$t_{d(off)}$		VUB 160	750	ns
$E_{on}$		VUB 120	11	mJ
$E_{off}$		VUB 160	12	mJ
$R_{thJC}$		VUB 120		0.22 K/W
		VUB 160		0.18 K/W
$R_{thCH}$		VUB 120	0.1	K/W
		VUB 160	0.1	K/W
$I_R$	$V_R = V_{RRM}, T_{VJ} = 25^{\circ}\text{C}$		0.75	0.5 mA
	$T_{VJ} = 125^{\circ}\text{C}$			1 mA
$V_F$	$I_F = 30 \text{ A}, T_{VJ} = 25^{\circ}\text{C}$			2.7 V
$V_{T0}$	For power-loss calculations only			1.3 V
$r_T$	$T_{VJ} = 150^{\circ}\text{C}$			15 mΩ
$I_{RM}$	$I_F = 50 \text{ A}, -di_F/dt = 100 \text{ A}/\mu\text{s}, V_R = 100 \text{ V}$		8	12 A
$t_{tr}$	$I_F = 1 \text{ A}, -di_F/dt = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		40	60 ns
$R_{thJC}$				0.9 K/W
			0.3	K/W

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